HMC392A

GaAs MMIC LOW NOISE AMPLIFIER, 3.5 - 7.0 GHz

Typical Applications
The HMC392A is ideal for:
• Point-to-Point Radios
• VSAT
• LO Driver for HMC Mixers
• Military EW, ECM, C^3I
• Space

Features
Gain: 17.2 dB
Noise Figure: 1.7 dB
Single Supply Voltage: +5V
50 Ohm Matched Input/Output
No External Components Required
Small Size: 1.3 x 1.0 x 0.1 mm

General Description
The HMC392A is a GaAs MMIC Low Noise Amplifier die which operates between 3.5 and 7.0 GHz. The amplifier provides 17.2 dB of gain, 1.7 dB noise figure, and 32.5 dBm IP3 from a +5V supply voltage. The HMC392A has six bonding adjustment options which allow the user to select the bias point and output power of the device (+10 to +19.7 dBm). The HMC392A amplifier can easily be integrated into Multi-Chip-Modules (MCMs) due to its small (1.3 mm^2) size. All data is with the chip in a 50 Ohm test fixture connected via 0.025mm (1 mil) diameter wire bonds of minimal length 0.31mm (12 mils).

Electrical Specifications, $T_A = +25^\circ C$, $Vdd = 5V$

<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency Range</td>
<td>4.0 - 6.0 GHz</td>
<td>3.5 - 7.0 GHz</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Gain</td>
<td>14.5</td>
<td>17.4</td>
<td>14.5</td>
<td>17.2</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Gain Variation Over Temperature</td>
<td>0.005</td>
<td>0.005</td>
<td>0.005</td>
<td>0.005</td>
<td></td>
<td></td>
<td>dB/°C</td>
</tr>
<tr>
<td>Noise Figure</td>
<td>1.7</td>
<td>3.0</td>
<td>1.7</td>
<td>3.4</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Input Return Loss</td>
<td>12</td>
<td>12</td>
<td>12</td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Output Return Loss</td>
<td>20</td>
<td></td>
<td>18</td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Output Power for 1 dB Compression (P1dB)</td>
<td>19.5</td>
<td>19</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Saturated Output Power (Psat)</td>
<td>20.5</td>
<td></td>
<td>20</td>
<td></td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Output Third Order Intercept (IP3)</td>
<td>32.5</td>
<td>32.5</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Supply Current (idd)</td>
<td>59</td>
<td>75</td>
<td>59</td>
<td>75</td>
<td></td>
<td></td>
<td>mA</td>
</tr>
</tbody>
</table>

Note: Data taken with pad PS2 bonded to ground (state 2) unless otherwise noted.

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GaAs MMIC LOW NOISE AMPLIFIER, 3.5 - 7.0 GHz

Broadband Gain & Return Loss

Gain vs. Temperature

Input Return Loss vs. Temperature

Output Return Loss vs. Temperature

Noise Figure vs. Temperature

Reverse Isolation vs. Temperature

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**Absolute Maximum Ratings**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Specification</th>
</tr>
</thead>
<tbody>
<tr>
<td>Drain Bias Voltage (Vdd)</td>
<td>+7 Vdc</td>
</tr>
<tr>
<td>RF Input Power (RFIN) (Vdd = +5 Vdc)</td>
<td>-20 dBm</td>
</tr>
<tr>
<td>Channel Temperature</td>
<td>175 °C</td>
</tr>
<tr>
<td>Continuous Pdiss (T= 85 °C) (derate 9.3 mW/°C above 85 °C)</td>
<td>0.83 W</td>
</tr>
<tr>
<td>Thermal Resistance (channel to die bottom)</td>
<td>108 °C/W</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-65 to +150 °C</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-55 to +85 °C</td>
</tr>
<tr>
<td>ESD</td>
<td>Class 1A</td>
</tr>
</tbody>
</table>

**Typical Supply Current vs. Vdd**

<table>
<thead>
<tr>
<th>Vdd (Vdc)</th>
<th>Idd (mA)</th>
</tr>
</thead>
<tbody>
<tr>
<td>+4.5</td>
<td>57</td>
</tr>
<tr>
<td>+5.0</td>
<td>59</td>
</tr>
<tr>
<td>+5.5</td>
<td>62</td>
</tr>
</tbody>
</table>

(State 2 Depicted)

**Die Packaging Information**

<table>
<thead>
<tr>
<th>Standard</th>
<th>Alternate</th>
</tr>
</thead>
<tbody>
<tr>
<td>WP-16 (Waffle Pack)</td>
<td>[2]</td>
</tr>
</tbody>
</table>

[1] Refer to the “Packaging Information” section for die packaging dimensions.

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**Pad Descriptions**

<table>
<thead>
<tr>
<th>Pad Number</th>
<th>Function</th>
<th>Description</th>
<th>Interface Schematic</th>
</tr>
</thead>
<tbody>
<tr>
<td>3</td>
<td>RFIN</td>
<td>This pad is AC coupled and matched to 50 Ohms</td>
<td><img src="image" alt="RFIN" /></td>
</tr>
<tr>
<td>5, 6, 7, 8, 9, 10</td>
<td>Power Select</td>
<td>One of these pads must be connected to ground. See Power Select Table for selection criteria.</td>
<td><img src="image" alt="Power Select" /></td>
</tr>
<tr>
<td>1, 2</td>
<td>Vdd, Vdd (alt.)</td>
<td>Power supply voltage. Connect either pad 1 or pad 2 to +5V supply. No choke inductor or bypass capacitor is needed.</td>
<td><img src="image" alt="Vdd" /></td>
</tr>
<tr>
<td>4</td>
<td>RFOUT</td>
<td>This pad is AC coupled and matched to 50 Ohms</td>
<td><img src="image" alt="RFOUT" /></td>
</tr>
<tr>
<td>Die Bottom</td>
<td>GND</td>
<td>Die bottom must be connected to RF/DC ground.</td>
<td><img src="image" alt="GND" /></td>
</tr>
</tbody>
</table>

**Power Select Table**

<table>
<thead>
<tr>
<th>State</th>
<th>Pads Bonded to Ground</th>
<th>Typical Idd (mA)</th>
<th>Typical P1dB (dBm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>PS1</td>
<td>69</td>
<td>19.7</td>
</tr>
<tr>
<td>2</td>
<td>PS2</td>
<td>59</td>
<td>19.4</td>
</tr>
<tr>
<td>3</td>
<td>PS3</td>
<td>49</td>
<td>18.8</td>
</tr>
<tr>
<td>4</td>
<td>PS4</td>
<td>38</td>
<td>17.5</td>
</tr>
<tr>
<td>5</td>
<td>PS5</td>
<td>27</td>
<td>14.8</td>
</tr>
<tr>
<td>6</td>
<td>PS6</td>
<td>17</td>
<td>10.3</td>
</tr>
</tbody>
</table>

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Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer’s schedule.

Wire Bonding

Ball or wedge bond with 0.025mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31mm (12 mils).

Note: State 2 shown. PS2 bonded to ground.